

ESAC39M(C,N,D) (5A)

(400V to 600V / 5A)

FAST RECOVERY DIODE

■ Features

- Insulated package by fully molding
- Super high speed switching
- Low VF in turn on
- High reliability

■ Applications

- High speed switching

■ Maximum ratings and characteristics

- Absolute maximum ratings

Item	Symbol	Conditions	Rating		Unit
			-04	-06	
Repetitive peak reverse voltage	V _{RPM}		400	600	V
Non-repetitive peak reverse voltage	V _{RSRM}		400	600	V
Isolating voltage	V _{iso}	Terminals-to-case, AC. 1 min.	1500		V
Average output current	I _O	Square wave, duty=1/2, T _c =110°C	5*		A
Surge current	I _{FSM}	Sine wave 10ms	20		A
Operating junction temperature	T _j		-40 to +150		°C
Storage temperature	T _{stg}		-40 to +150		°C

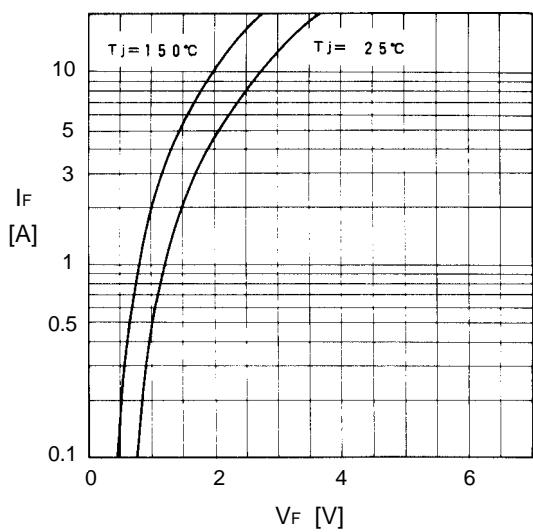
*Average forward current of centertap full wave connection

- Electrical characteristics (Ta=25°C Unless otherwise specified)

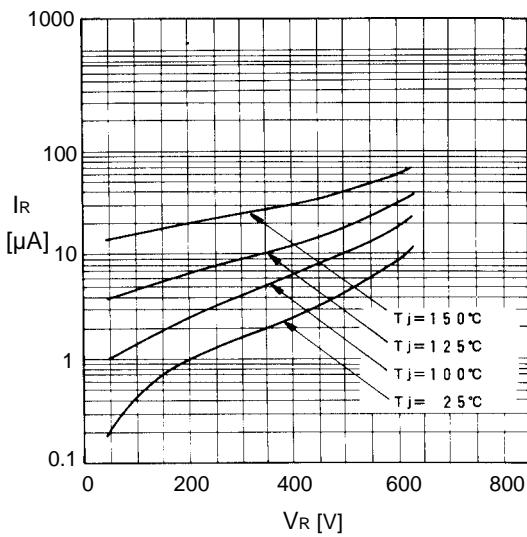
Item	Symbol	Conditions	Max.	Unit
Forward voltage drop	V _{FM}	I _{FM} =2A	2.5	V
Reverse current	I _{RRM}	V _R =V _{RPM}	100	µA
Reverse recovery time	t _{rr}	I _F =0.1A, I _R =0.2A, I _{rec} =0.05A	50	ns
Thermal resistance	R _{th(j-c)}	Junction to case	3.5	°C/W

■ Characteristics

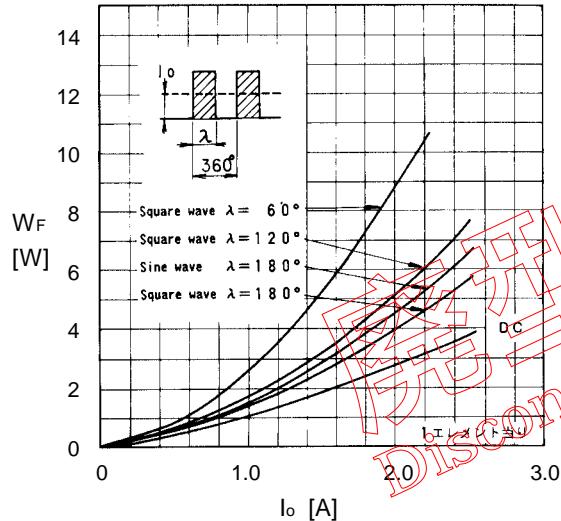
Forward characteristics



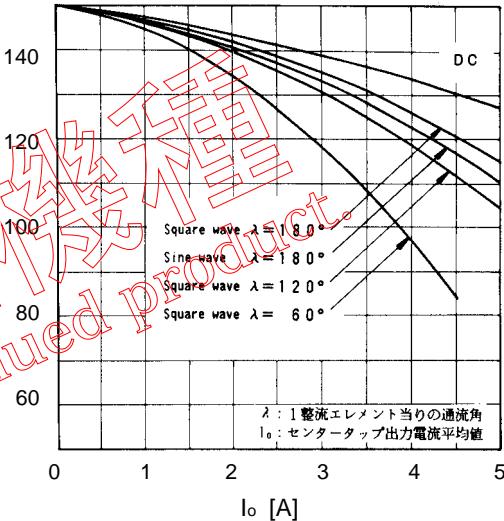
Reverse characteristics



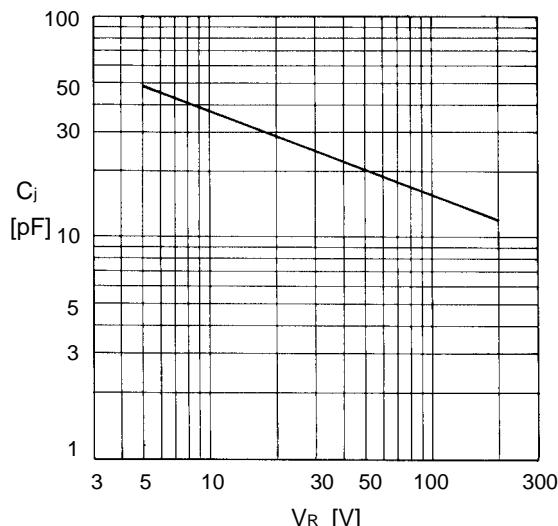
Forward power dissipation



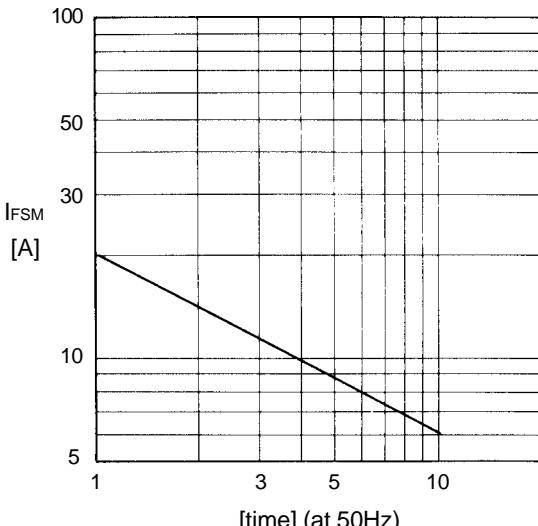
Output current-case temperature



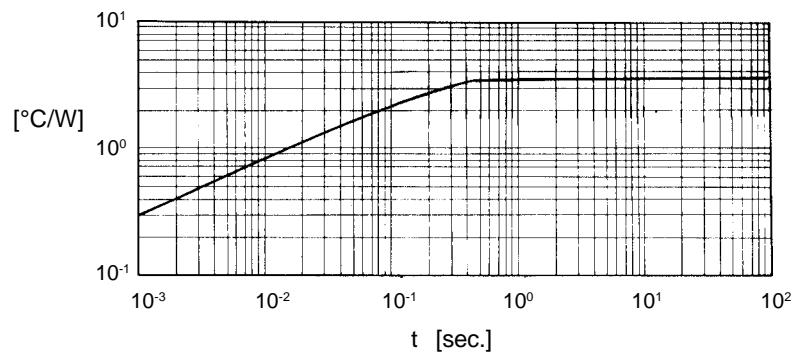
Junction capacitance characteristics



Surge capability



Transient thermal impedance



密型核子種
Discontinued product.